

Dual P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)			
- 30	0.025 at V _{GS} = - 10 V	- 7.1			
- 30	0.041 at V _{GS} = - 4.5 V	- 5.5			

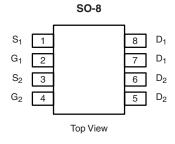
FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- Compliant to RoHS Directive 2002/95/EC

ROHS COMPLIANT HALOGEN FREE

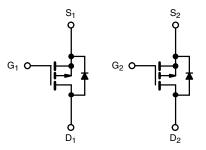
APPLICATIONS

- Load Switches
 - Notebook PCs
 - Desktop PCs
 - Game Stations



Ordering Information: Si4925BDY-T1-E3 (Lead (Pb)-free)

Si4925BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted						
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	- 30		V	
Gate-Source Voltage		V _{GS}	± 20			
Continuous Drain Current /T 150 °C\8	T _A = 25 °C	- 7.1 - 5.7	- 7.1	- 5.3		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 5.7	- 4.3		
Pulsed Drain Current		I _{DM}	- 40		Α	
Continuous Source Current (Diode Conduction) ^a		I _S	- 1.7	- 0.9		
Mariana Barra Biraira di ang	T _A = 25 °C	- P _D	2.0	1.1	W	
Maximum Power Dissipation ^a	T _A = 70 °C	' D	1.3	0.7]	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mariana barria ta Andria 18	t ≤ 10 s	R _{thJA}	50	62.5	
Maximum Junction-to-Ambient ^a	Steady State	' 'thJA	85	110	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	30	40	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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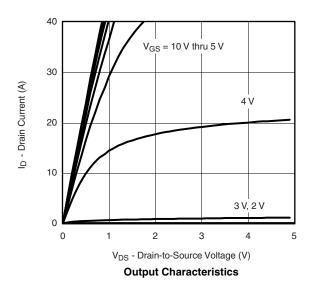
SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1		- 3	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zara Cata Valtaga Drain Current	1	V _{DS} = - 30 V, V _{GS} = 0 V			- 1		
Zero Gate Voltage Drain Current	IDSS	V _{DS} = - 30 V, V _{GS} = 0 V, T _J = 55 °C			- 25	μΑ	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 10 V	- 40			Α	
	D	V _{GS} = - 10 V, I _D = - 7.1 A		0.020	0.025	0	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -5.5 \text{ A}$		0.033	0.041	Ω	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 7.1 A		20		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 1.7 A, V _{GS} = 0 V		- 0.8	- 1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			33	50		
Gate-Source Charge	Q_{gs}	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -7.1 \text{ A}$		5.4		nC	
Gate-Drain Charge	Q _{gd}			8.9			
Turn-On Delay Time	t _{d(on)}			9	15		
Rise Time	t _r	V_{DD} = - 15 V, R_L = 15 Ω		12	20		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ - 1 A, $V_{GEN}=$ - 10 V, $R_g=$ 6 Ω		60	90	ns	
Fall Time	t _f			34	50		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.7 A, dl/dt = 100 A/μs		30	60		

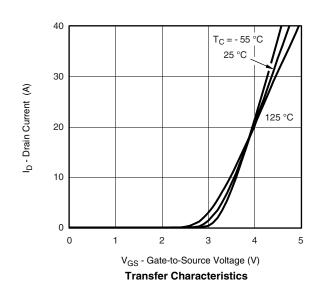
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

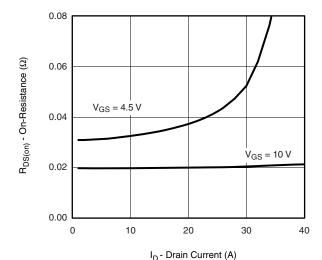
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



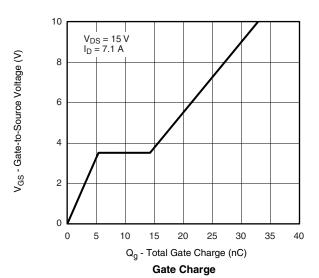


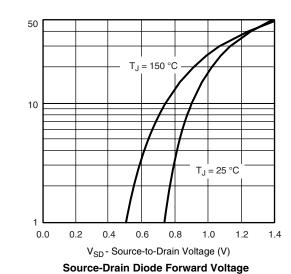


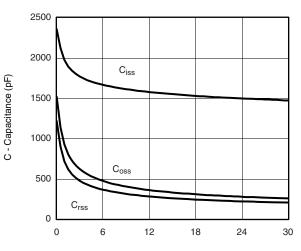
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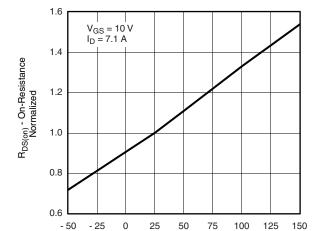
On-Resistance vs. Drain Current





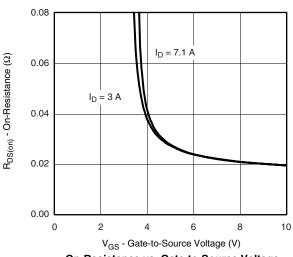


V_{DS} - Drain-to-Source Voltage (V) **Capacitance**



T_J- Junction Temperature (°C)

On-Resistance vs. Junction Temperature

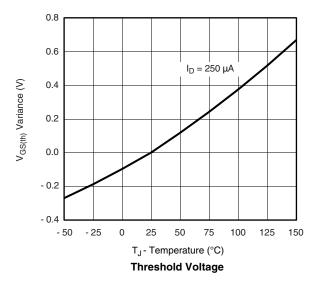


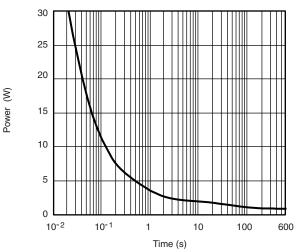
On-Resistance vs. Gate-to-Source Voltage

I_S - Source Current (A)

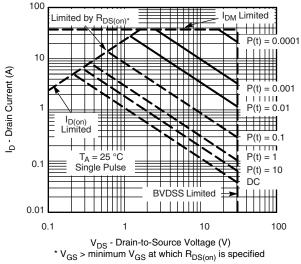
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

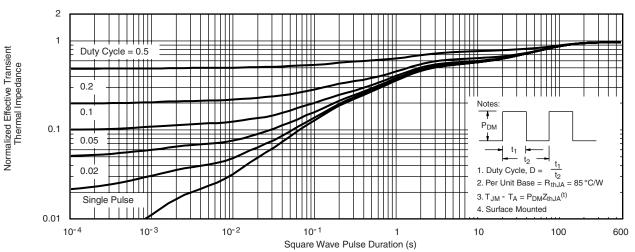




Single Pulse Power



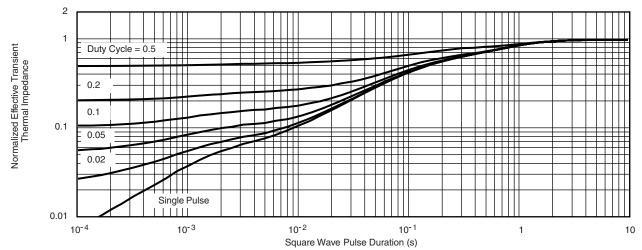
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

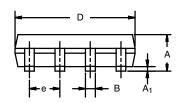
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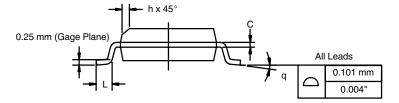
Document Number: 72001 S09-0869-Rev. D, 18-May-09



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INCHES			
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I. 11-Sep-06						

DWG: 5498

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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